NSN 5961-01-220-8207

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Inclosure Material:

Metal

Overall Length:

Between 1.553 inches and 1.573 inches

Overall Height:

0.905 inches

Overall Width:

1.050 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Electrostatic sensitive and hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

1400.0 collector to base voltage/static/emitter open and 1000.0 collector to emitter voltage/static/base open and 1400.0 collector to emitter

voltage, dc with specified circuit between base and emitter and 5.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

Between 2.00 amperes source cutoff current and 5.00 amperes source cutoff current

Power Rating Per Characteristic:

100.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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